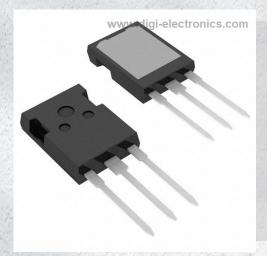


IXFX32N80Q3 Datasheet



https://www.DiGi-Electronics.com

DiGi Electronics Part Number IXFX32N80Q3-DG

Manufacturer IXYS

Manufacturer Product Number IXFX32N80Q3

Description MOSFET N-CH 800V 32A PLUS247-3

Detailed Description N-Channel 800 V 32A (Tc) 1000W (Tc) Through Hole

PLUS247TM-3



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RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.



Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
IXFX32N80Q3	IXYS
Series:	Product Status:
HiPerFET™, Q3 Class	Active
FET Type:	Technology:
N-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:
800 V	32A (Tc)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ Id, Vgs:
10V	270mOhm @ 16A, 10V
Vgs(th) (Max) @ Id:	Gate Charge (Qg) (Max) @ Vgs:
6.5V @ 4mA	140 nC @ 10 V
Vgs (Max):	Input Capacitance (Ciss) (Max) @ Vds:
±30V	6940 pF @ 25 V
FET Feature:	Power Dissipation (Max):
	1000W (Tc)
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Through Hole
Supplier Device Package:	Package / Case:
PLUS247™-3	TO-247-3 Variant
Base Product Number:	
IXFX32	

Environmental & Export classification

8541.29.0095

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	



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